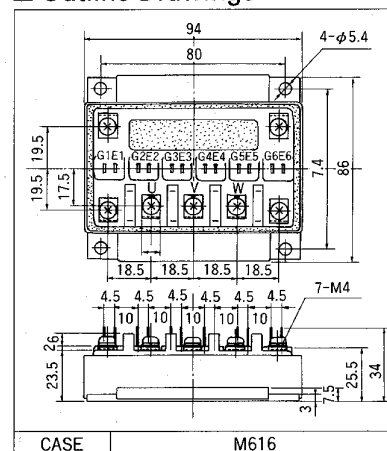


FUJI
ELECTRIC**6MBI 50L-060****6-Pack IGBT**
600 V
50 A**IGBT MODULE (L series)****■ Features**

- High Speed Switching
- Low Saturation Voltage
- Voltage Drive

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial Machines, such as Welding Machines

■ Outline Drawings**■ Maximum Ratings and Characteristics****● Absolute Maximum Ratings**

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V _{CEs}	600	V
Gate-Emitter Voltage	V _{GES}	±20	V
Collector Current	Continuous	I _c	50
	1ms	I _c pulse	100
	Continuous	-I _c	50
	1ms	-I _c pulse	100
Max. Power Dissipation	P _c	250	W
Operating Temperature	T _j	+150	°C
Storage Temperature	T _{stg}	-40 to +125	°C
Net. Weight		510	g
Isolation Voltage	AC, 1min.	V _{isol}	2500
Screw Torque	Mounting *1	35	kg•cm
	Terminals *2	17	

*1 Recommendable Value 25 to 35kg•cm (M5)

*2 Recommendable Value 13 to 17kg•cm (M4)

● Electrical Characteristics (T_j=25°C)

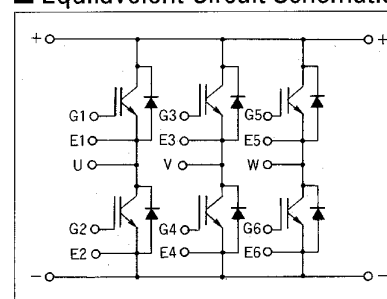
Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I _{ces}	V _{GE} =0V V _{CE} =600V T _j =25°C			1.0	mA
Gate-Emitter Leakage Current	I _{GES}	V _{CE} =0V V _{GE} =±20V			100	nA
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{CE} =20V I _c =50mA	3.0		6.0	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V I _c =50A		2.7	3.5	V
Input Capacitance	C _{ies}	V _{GE} =0V		4750		pF
Output Capacitance	C _{oes}	V _{CE} =10V		-		pF
Reverse Transfer Capacitance	C _{res}	f=1MHz		-		pF
Turn-on Time *3	t _{on}	V _{CC} =300V		0.4	0.8	μs
	t _r	I _c =50A		0.3	0.6	μs
Turn-off Time *4	t _{off}	V _{GE} =±15V		0.6	1.0	μs
	t _r	R _G =51Ω		0.2	0.35	μs
Diode Forward On-Voltage	V _F	I _F =50A V _{GE} =0V			2.5	V
Reverse Recovery Time	t _{rr}	I _F =50A -di/dt=150A/μs V _{GE} =-10V			300	ns

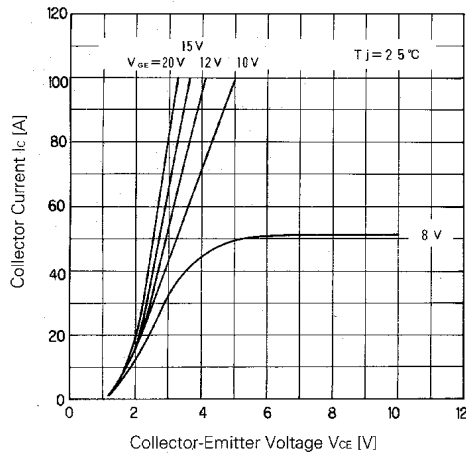
*3 Resistive load

*4 Inductive load

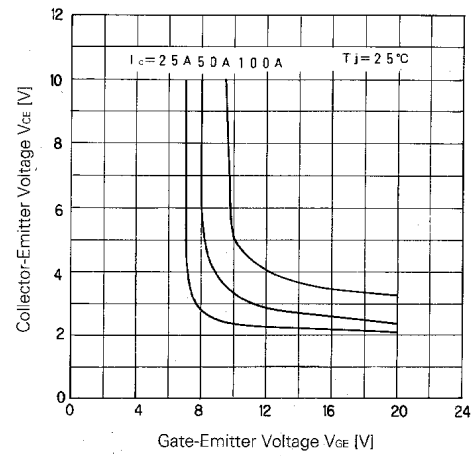
● Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R _{th(j-c)}	IGBT			0.5	°C/W
	R _{th(j-e)}	Diode			1.0	°C/W
	R _{th(c-t)}	With Thermal compound		0.05		°C/W

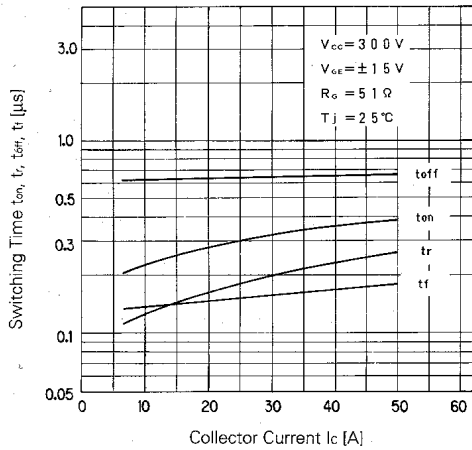
■ Equilavelent Circuit Schematic

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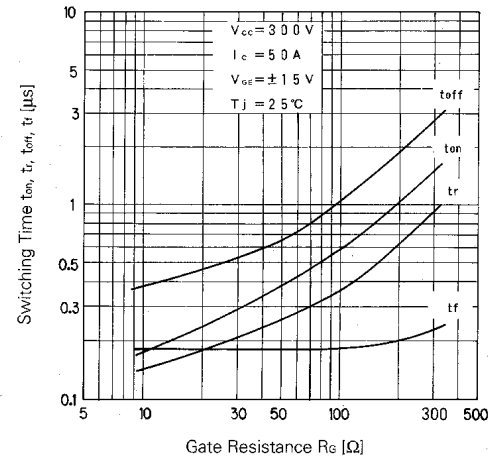
Collector Current vs. Collector-Emitter Voltage



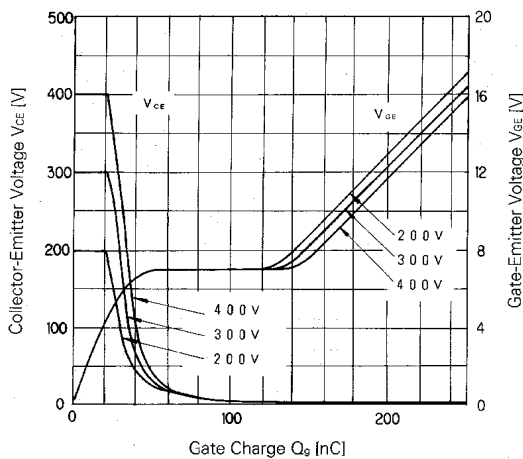
Collector-Emitter Voltage vs. Gate-Emitter Voltage



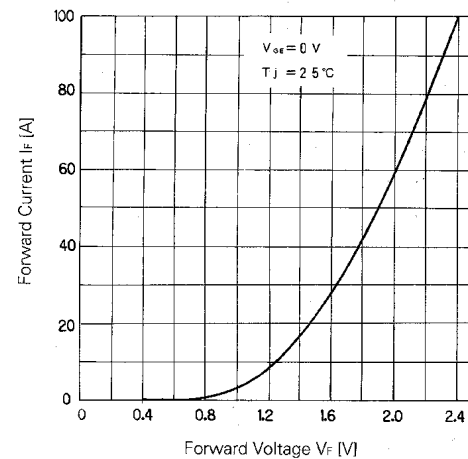
Switching Time



Switching Time-Gate Resistance



Dynamic Input Characteristic



Forward Voltage of Free Wheel Diode

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